



**炬芯微**  
XUANXINWEI

# MURF2005 THRU MURF2060

## SUPER FAST RECOVERY SILICON RECTIFIER

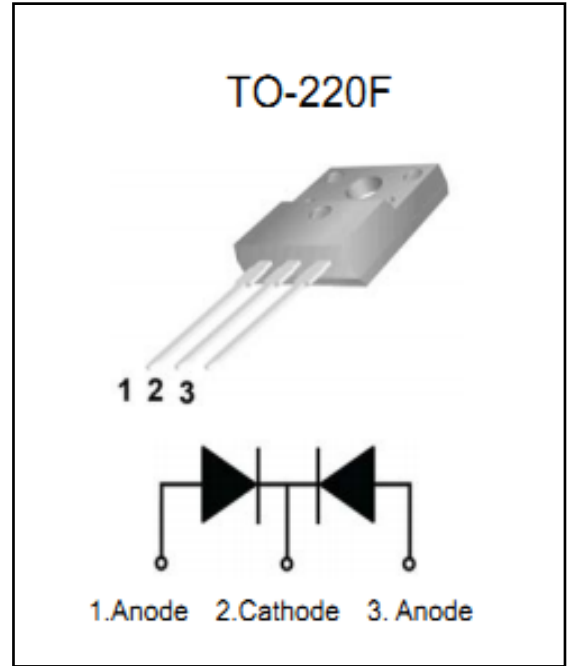
Reverse Voltage - 50 to 600 Volts      Forward Current - 20.0 Ampere

### FEATURES

- Glass Passivated Die Construction
- Super-Fast Switching
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O

### MECHANICAL DATA

- Case: ITO-220AC, Full Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- Mounting Torque: 11.5 cm·kg (10 in·lbs) Max.



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	MURF 2005	MURF 2010	MURF 2015	MURF 2020	MURF 2030	MURF 2040	MURF 2060	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$								
Working Peak Reverse Voltage	$V_{RWM}$	50	100	150	200	300	400	600	V
DC Blocking Voltage	$V_R$								
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	420	V
Average Rectified Output Current @ $T_C = 100^\circ\text{C}$	$I_o$	20.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	200							A
Forward Voltage @ $I_F = 20.0\text{A}$	$V_{FM}$	0.95				1.3		1.7	V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	$I_{RM}$	10 400							$\mu\text{A}$
Reverse Recovery Time (Note 1)	$t_{rr}$	35				50			nS
Typical Junction Capacitance (Note 2)	$C_j$	170				150			pF
Operating and Storage Temperature Range	$T_j, T_{STG}$	-65 to +150							$^\circ\text{C}$

Note: 1. Measured with  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $IRR = 0.25\text{A}$ .  
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



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# MURF2005 THRU MURF2060 RATINGS AND CHARACTERISTIC CURVES

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

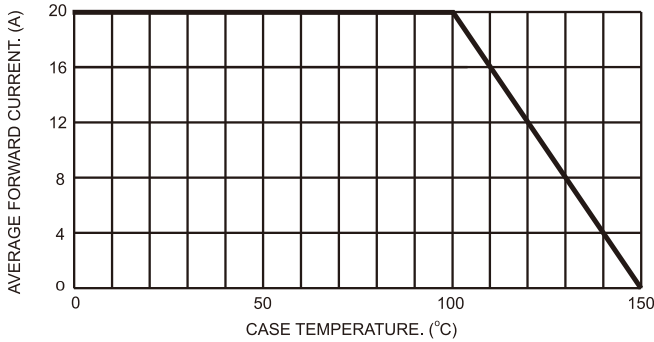


FIG.2- TYPICAL REVERSE CHARACTERISTICS

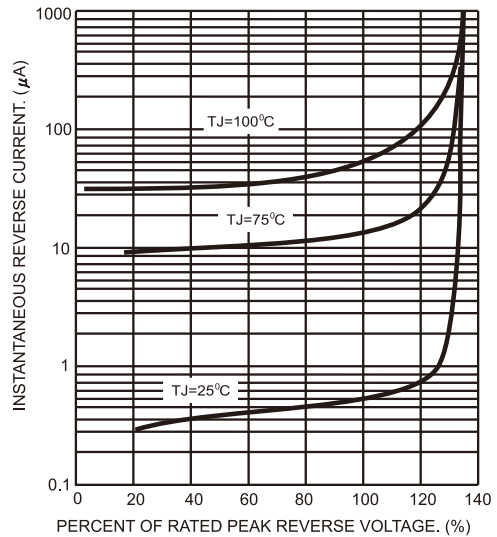


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

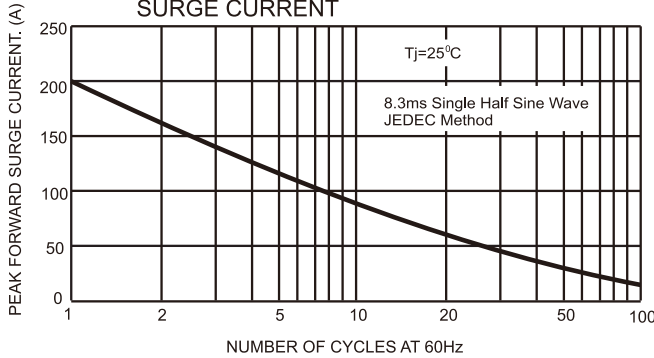


FIG.5- TYPICAL FORWARD CHARACTERISTICS

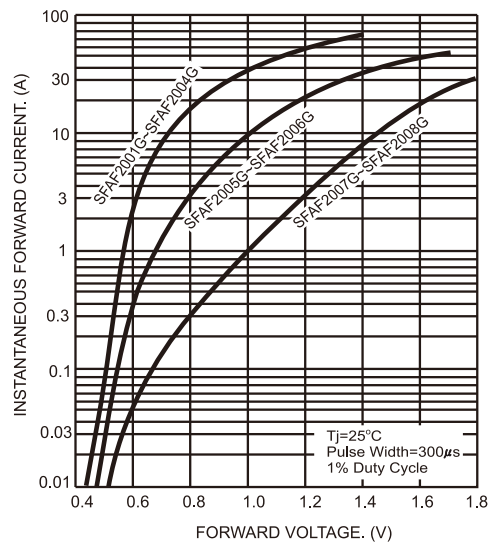


FIG.4- TYPICAL JUNCTION CAPACITANCE

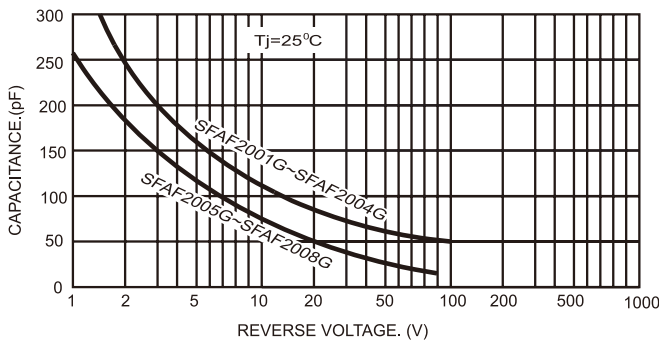
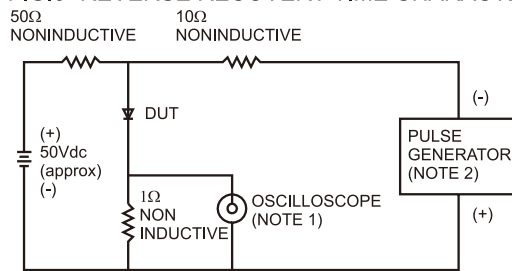
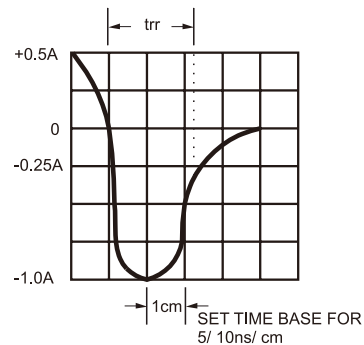


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance=1 megohm 22pf  
2. Rise Time=10ns max. Source Impedance=50 ohms





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## RATINGS AND CHARACTERISTIC CURVES

### Package Dimension

TO-220F

Unit: mm

